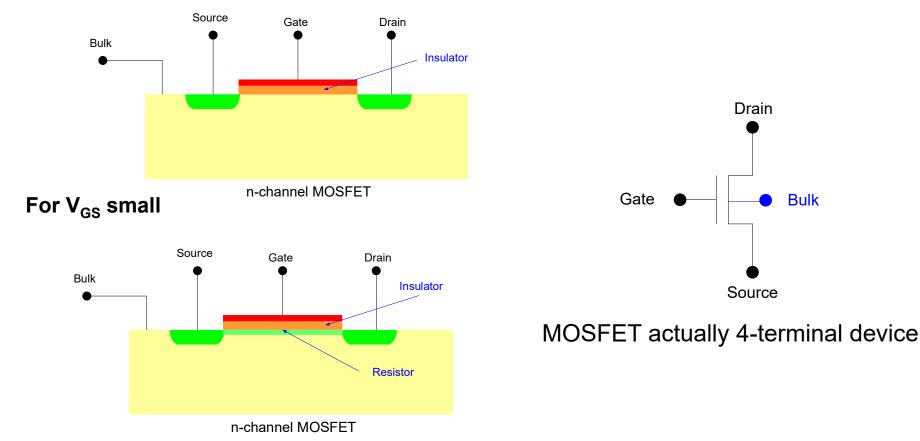
EE 330 Lecture 7

- Propagation Delay
- Stick Diagrams
- Technology Files
 - Design Rules

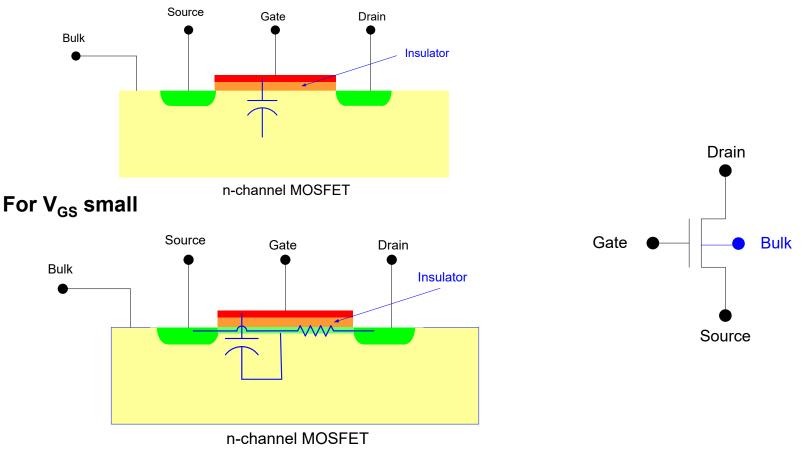
Review from Last Time MOS Transistor Qualitative Discussion of n-channel Operation



For V_{GS} large

- Region under gate termed the "channel"
- When "resistor" is electrically created, region where it resides in channel is termed an "inversion region"

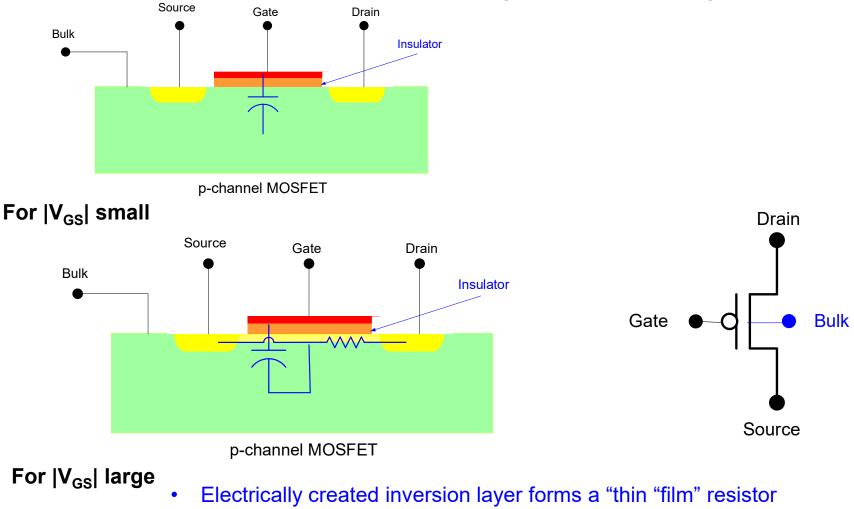
Review from Last Time MOS Transistor Qualitative Discussion of n-channel Operation



- For V_{GS} large
- Electrically created inversion layer forms a "thin "film" resistor
- Capacitance from gate to <u>channel region</u> is distributed
- Lumped capacitance much easier to work with

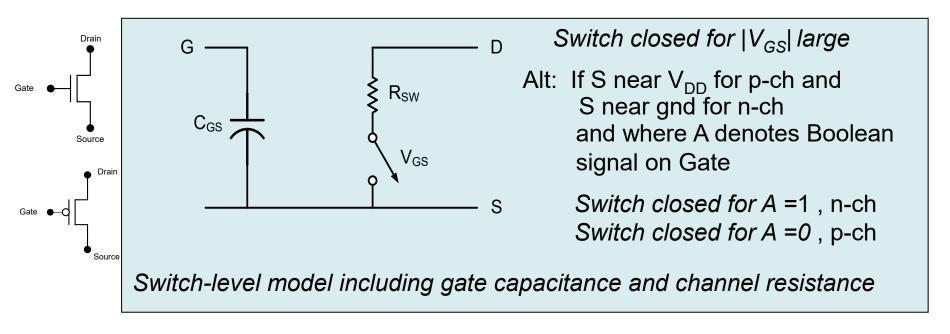
Review from Last Time MOS Transistor

Qualitative Discussion of p-channel Operation



- Capacitance from gate to <u>channel region</u> is distributed
- Lumped capacitance much easier to work with

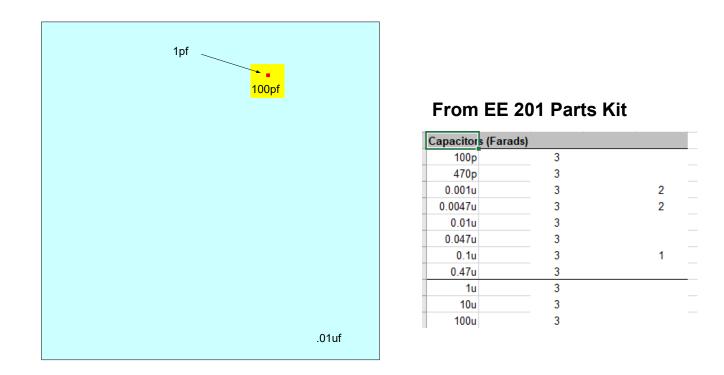
Review from Last Time Improved Switch-Level Model



 C_{GS} and R_{SW} dependent upon device sizes and process For minimum-sized devices in a 0.5u process with $V_{DD}=5V$ $C_{GS} \cong 1.5 \text{fF}$ $R_{sw} \cong \begin{array}{c} 2K\Omega & n-channel \\ 6K\Omega & p-channel \end{array}$

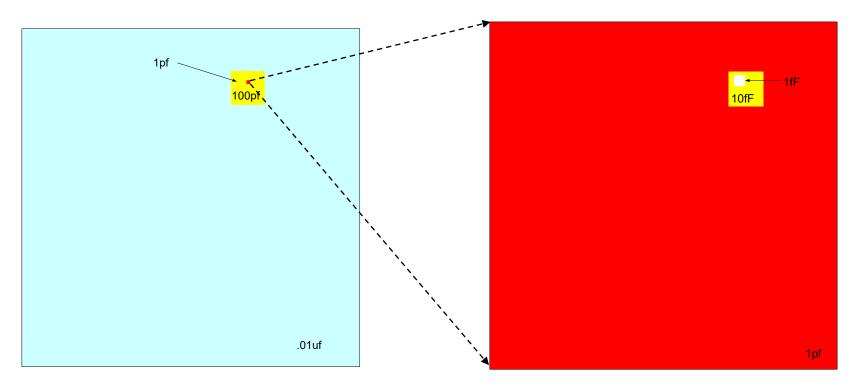
Considerable emphasis will be placed upon device sizing to manage C_{GS} and R_{SW}

Review from Last Time Is a capacitor of 1.5fF small enough to be neglected?



Area allocations shown to relative scale:

Review from Last Time Is a capacitor of 1.5fF small enough to be neglected?

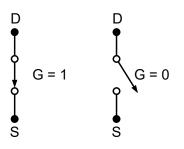


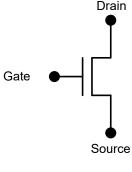
Area allocations shown to relative scale:

- Not enough information at this point to determine whether this very small capacitance can be neglected
- Will answer this important question later

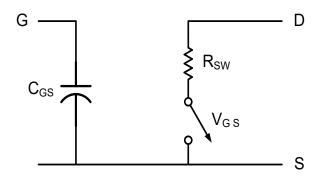








2. Improved switch-level model

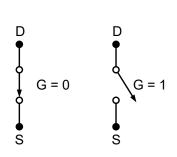


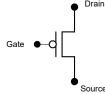
Switch closed for V_{GS} = large Switch open for V_{GS} = small

Other models will be developed later

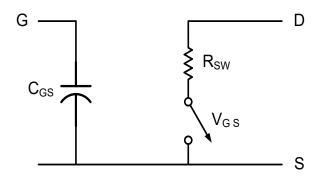
Review from Last Time Model Summary (for p-channel)







2. Improved switch-level model



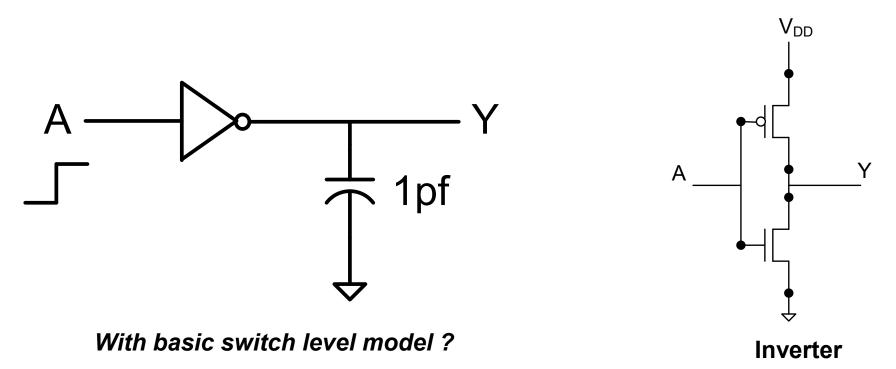
Switch closed for $|V_{GS}|$ = large Switch open for $|V_{GS}|$ = small

Other models will be developed later

Propagation Delay

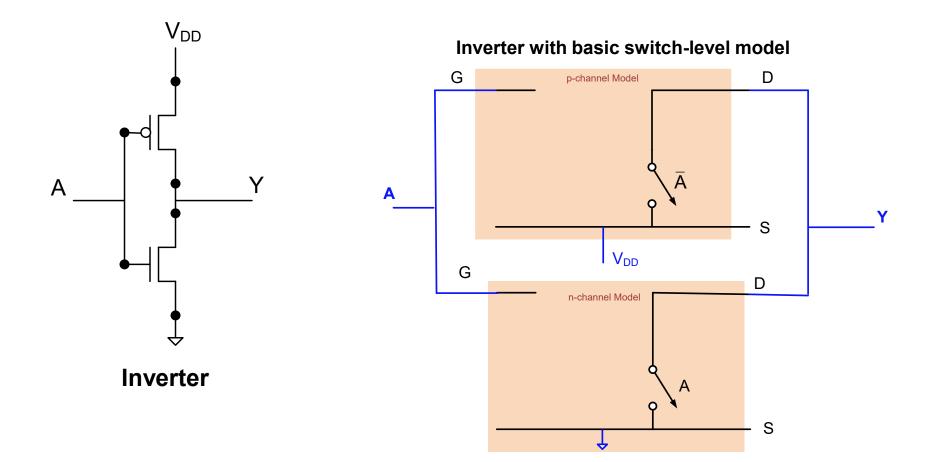
Example What are t_{HL} and t_{LH}?

Assume V_{DD}=5V

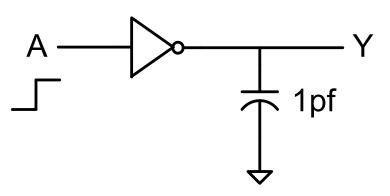


With improved switch level model ?

Example

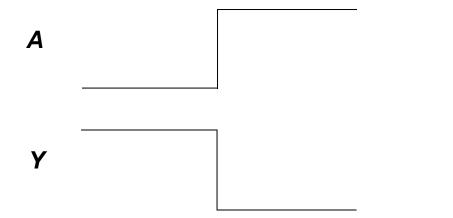


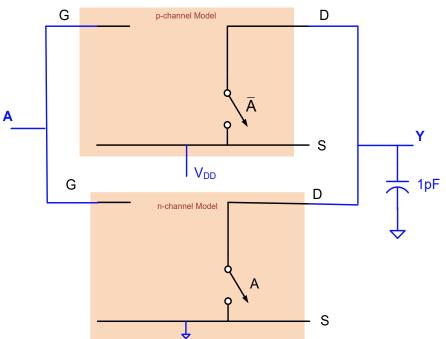
Example What are t_{HL} and t_{LH} at output?



Assume ideal step at A input

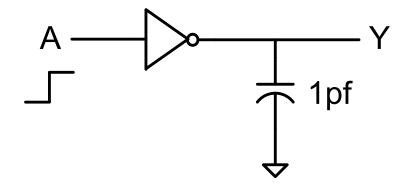
With basic switch level model





t_{HL}=t_{LH}=0

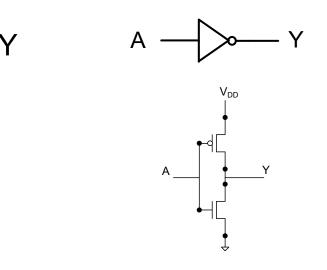
With simple switch-level model t_{HL}=t_{LH}=0



With improved model ?

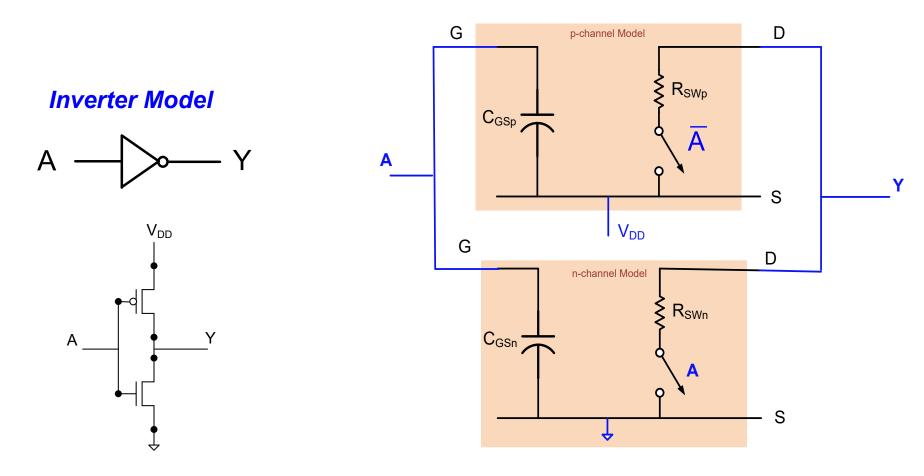
Α

Inverter Model?



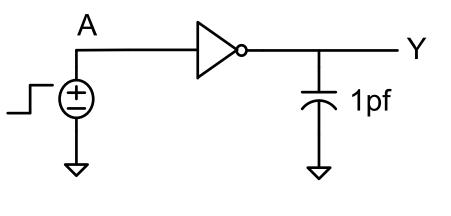
1pf

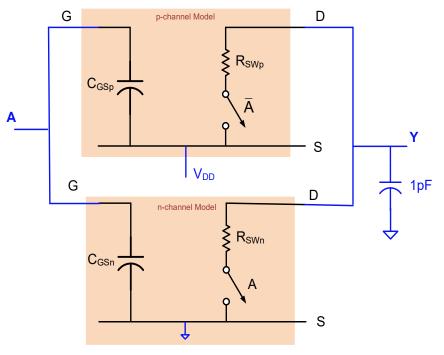
Inverter with improved model



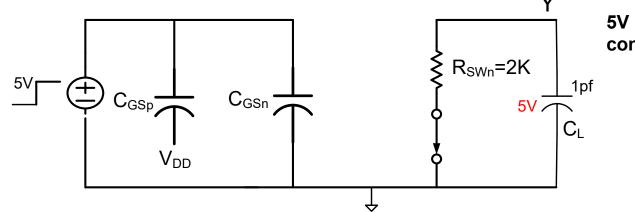
Inverter with Improved Model

With improved model t_{HL}=?

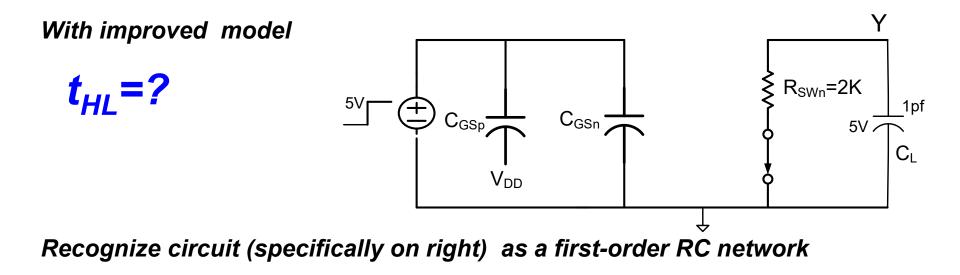




To initiate a HL output transisition, assume Y has been in the high state for a long time and lower switch closes at time t=0



5V is the initial condition on C_L



Recall: Step response of any first-order network with LHP pole can be written as

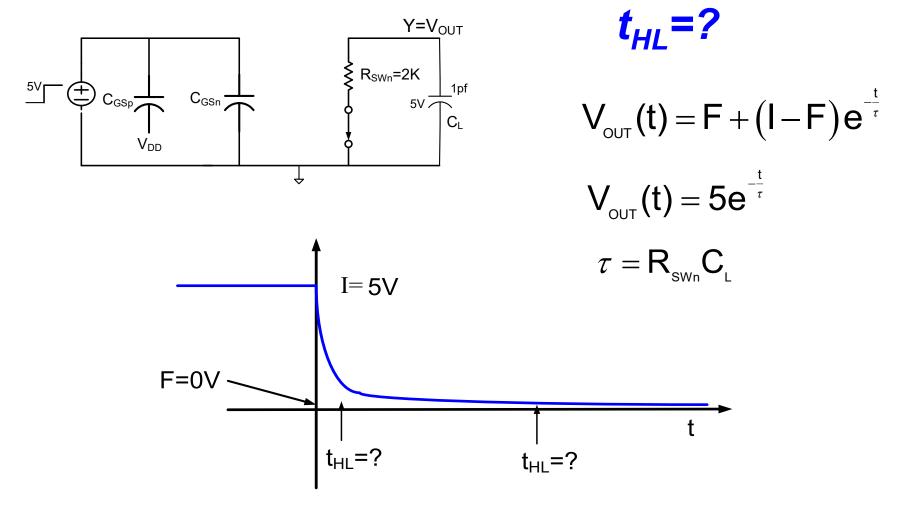
$$\mathbf{y}(\mathbf{t}) = \mathbf{F} + (\mathbf{I} - \mathbf{F}) \mathbf{e}^{-\frac{1}{\tau}}$$

where F is the final value, I is the initial value and T is the time constant of the circuit

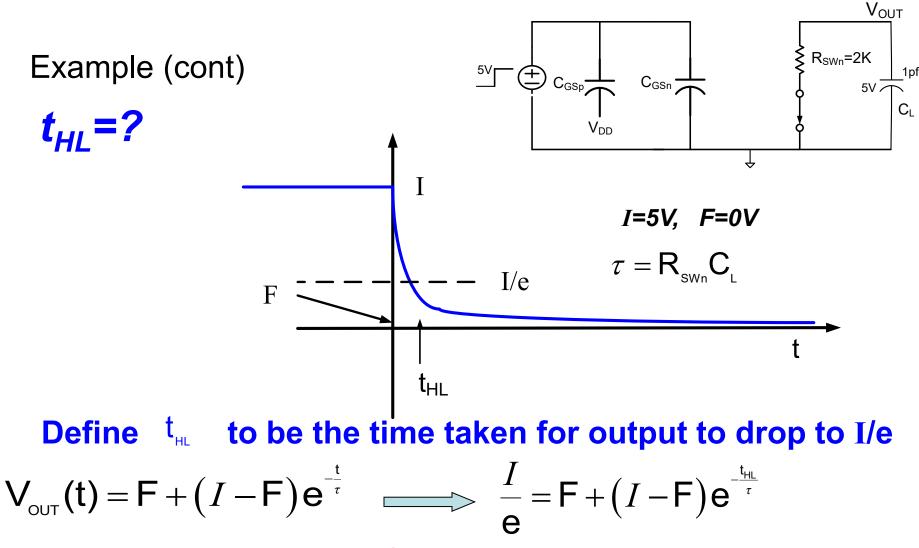
(from Chapter 7 of Nilsson and Riedel)

For the circuit above, F=0, I=5 and $\tau = R_{swn}C_{L}$

With improved model

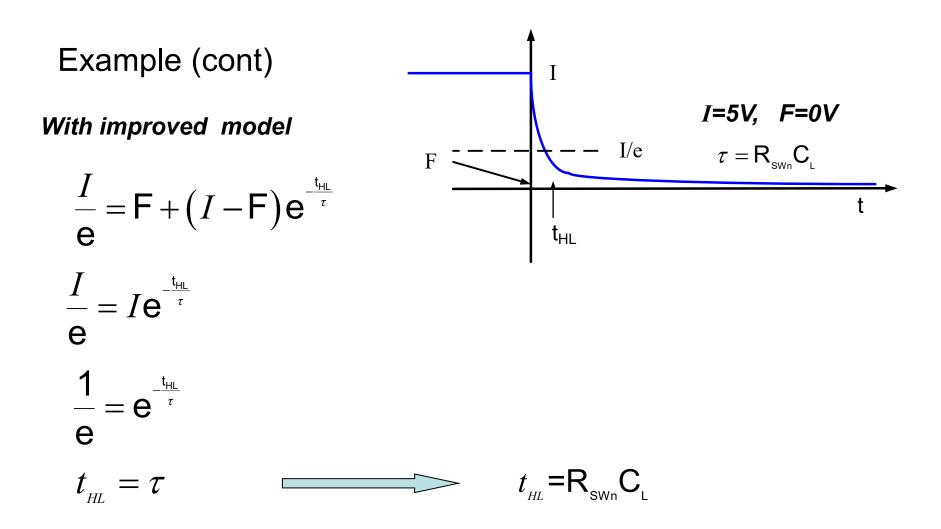


how is t_{HL} defined?



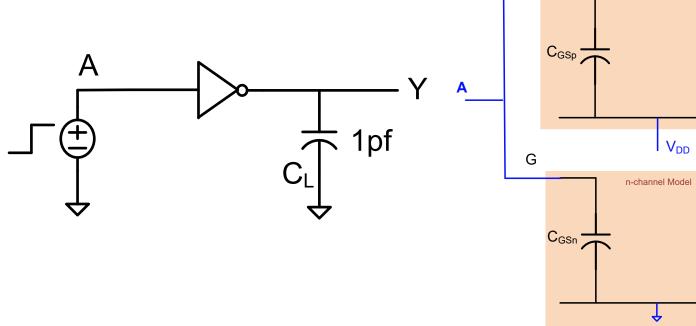
Is this simply a mathematical definition or does it have some practical significance?

 t_{HL} as defined here and as verified by experimental verification has proven useful at analytically predicting response time of circuits



Both experimental results and accurate computer simulations show that this reasonably accurately predicts how quickly following stages recognize that a logic transition has taken place !!

With improved model **t**_{LH}=?



Assume output in low state for a long time and upper switch closes at time t=0

G

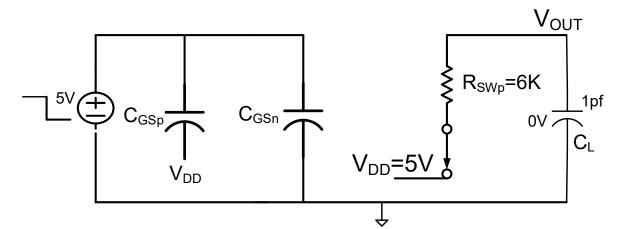
p-channel Model

R_{SWp}

Ā

 R_{SWn}

Α



0V is the initial condition on C_L

D

S

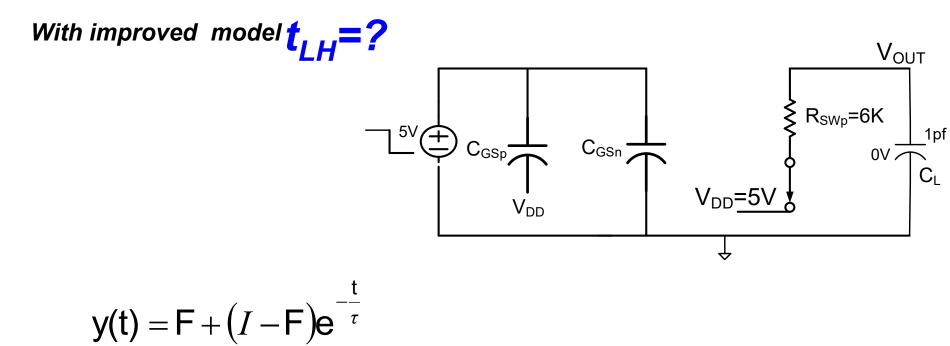
D

S

Υ

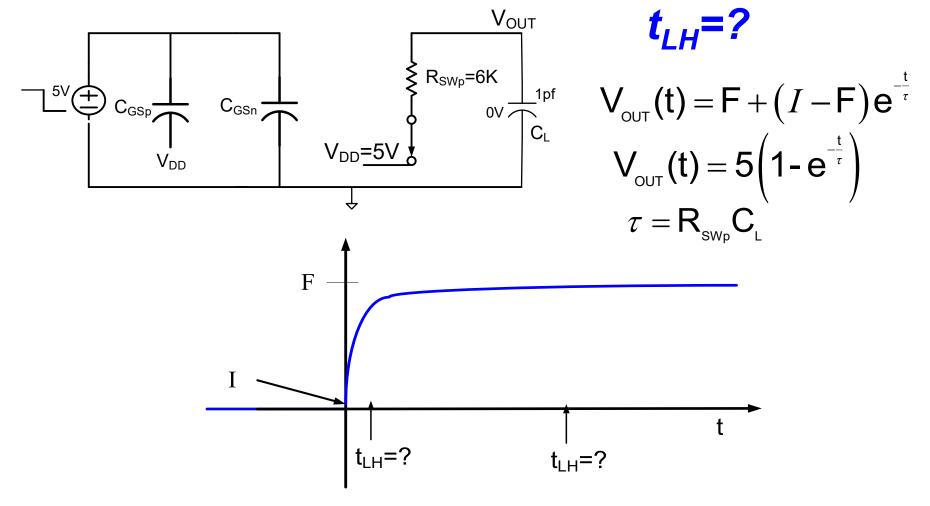
1pF

Α

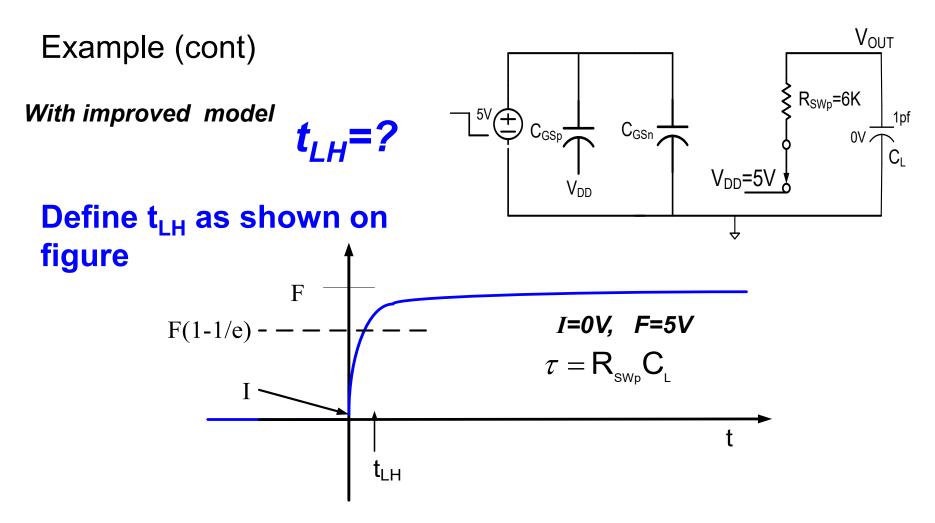


For this circuit (specifically on the right), F=5, I=0 and $\tau = R_{sub}C_{I}$

With improved model

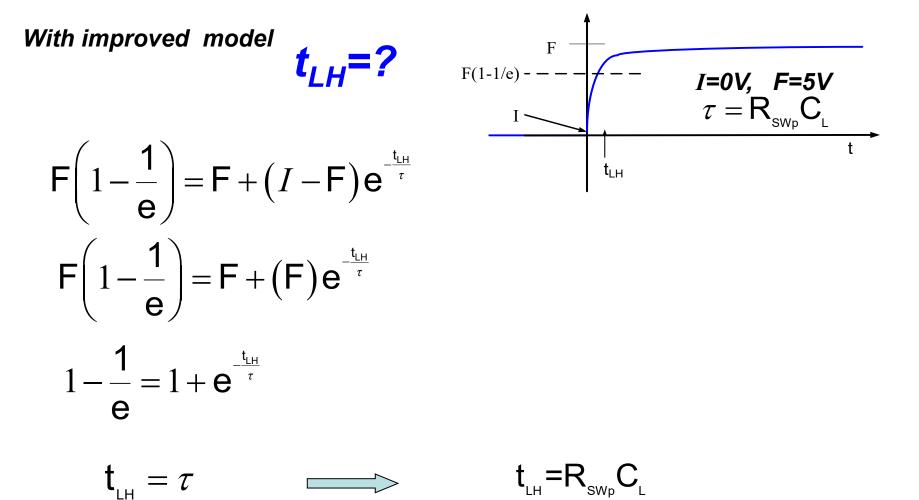


how is t_{LH} defined?

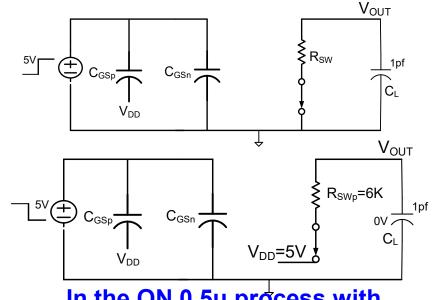


t_{LH} as defined has proven useful for analytically predicting response time of circuits

$$V_{out}(t) = F + (I - F)e^{-\frac{t}{\tau}} \qquad \Longrightarrow \qquad F\left(1 - \frac{1}{e}\right) = F + (I - F)e^{-\frac{t_{LH}}{\tau}}$$



With improved model



In the ON 0.5u process with minimum-sized devices

$$\mathbf{t}_{_{\mathrm{HL}}} \cong \mathbf{R}_{_{\mathrm{SWn}}} \mathbf{C}_{_{\mathrm{L}}} = 2K \cdot 1pF = 2n \operatorname{sec}$$

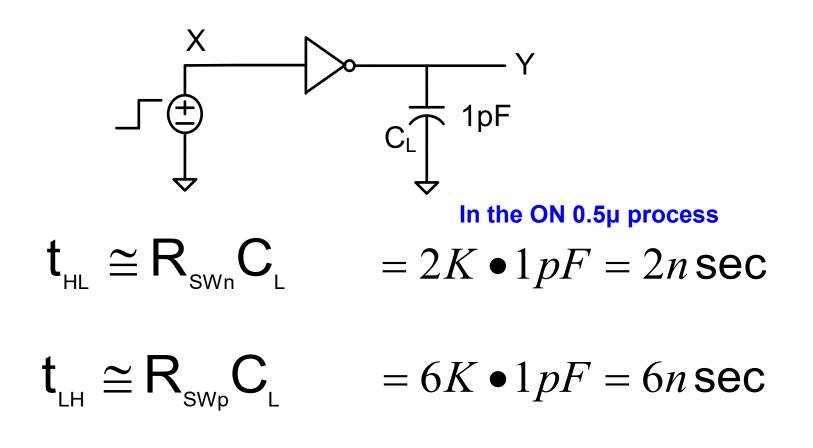
 $\mathbf{t}_{_{\mathrm{LH}}} \cong \mathbf{R}_{_{\mathrm{SWp}}} \mathbf{C}_{_{\mathrm{L}}} = 6K \cdot 1pF = 6n \operatorname{sec}$

Note this circuit is quite fast !

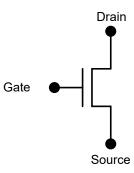
Note that t_{HL} is much shorter than t_{LH}

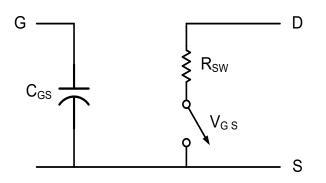
Often C_L will be even smaller and the circuit will be much faster !!

Summary: What is the delay of a minimum-sized inverter driving a 1pF load?



Improved switch-level model





Switch closed for V_{GS}= large

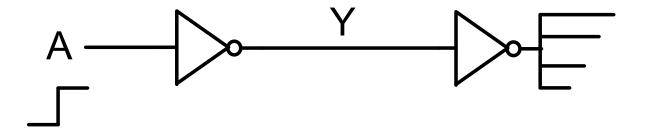
Switch open for V_{GS} = small

- Previous example showed why R_{sw} in the model was important
- But of what use is the C_{GS} which did not enter the previous calculations?

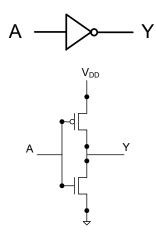
For minimum-sized devices in a 0.5µ process

$$\mathbf{C}_{GS} \cong \mathbf{1.5fF} \qquad \mathbf{R}_{sw} \cong \begin{array}{c} \mathbf{2K\Omega} & \mathbf{n} - \mathbf{channel} \\ \mathbf{6K\Omega} & \mathbf{p} - \mathbf{channel} \end{array}$$

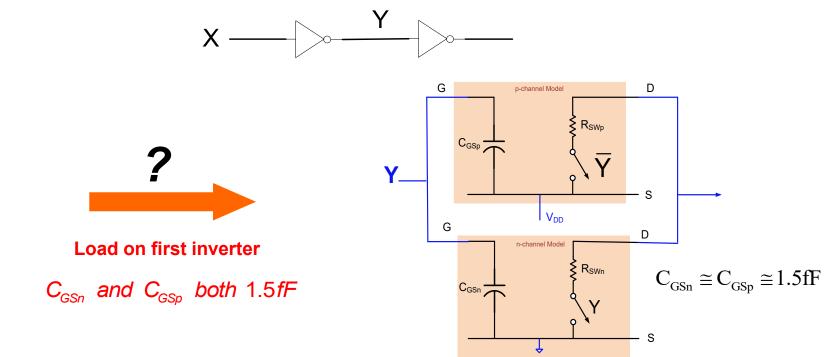
One gate often drives one or more other gates !



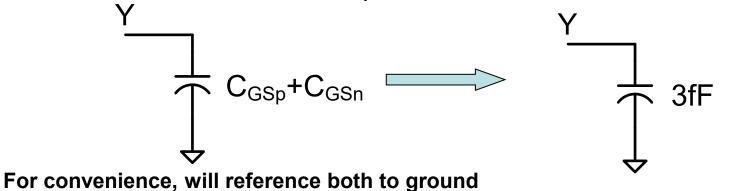
What are t_{HL} and t_{LH}?



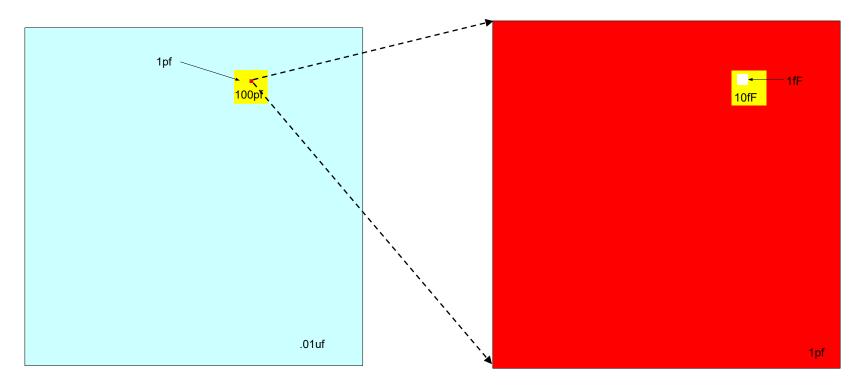
Example: What is the delay of a minimum-sized inverter driving another identical device?



Loading effects same whether C_{GSp} and/or C_{GSn} connected to V_{DD} or GND

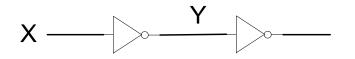


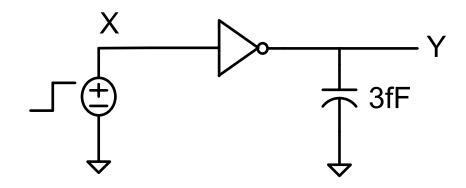
Is a capacitor of 1.5fF small enough to be neglected?



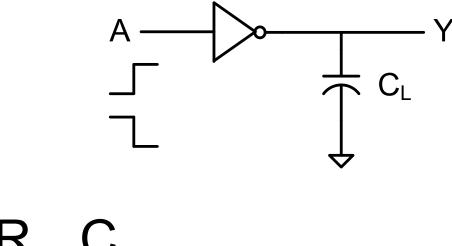
Area allocations shown to relative scale:

 This example will provide insight into the answer of the question Example: What is the delay of a minimum-sized inverter driving another identical device? Assume V_{DD} =5V

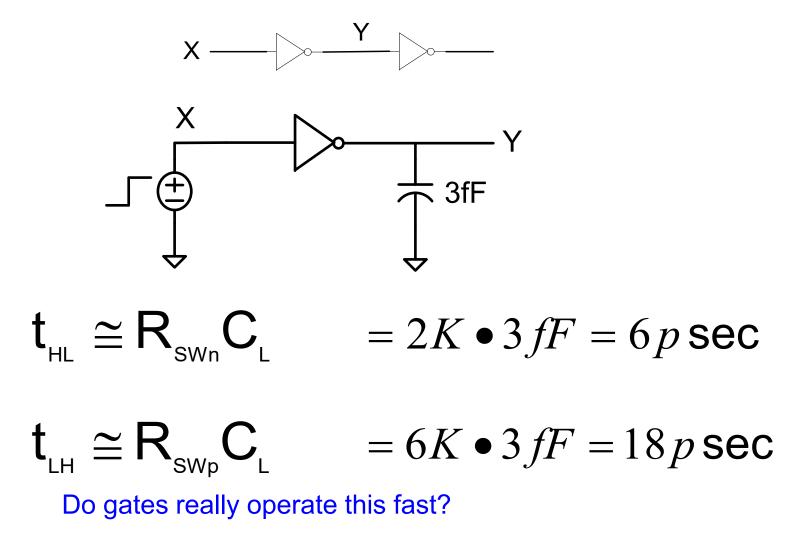




Generalizing the Previous Analysis to Arbitrary Load

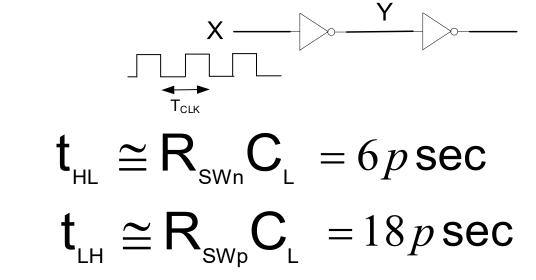


 $t_{HL} \cong R_{SWn}C_{L}$ $t_{LH} \cong R_{SWp}C_{L}$ Example: What is the delay of a minimum-sized inverter driving another identical device?

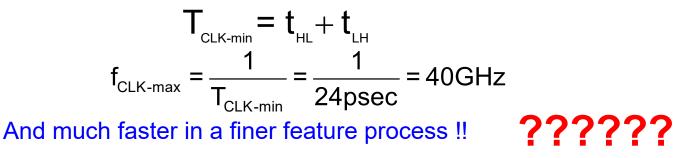


What would be the maximum clock rate for acceptable operation?

Example: What is the delay of a minimum-sized inverter driving another identical device?

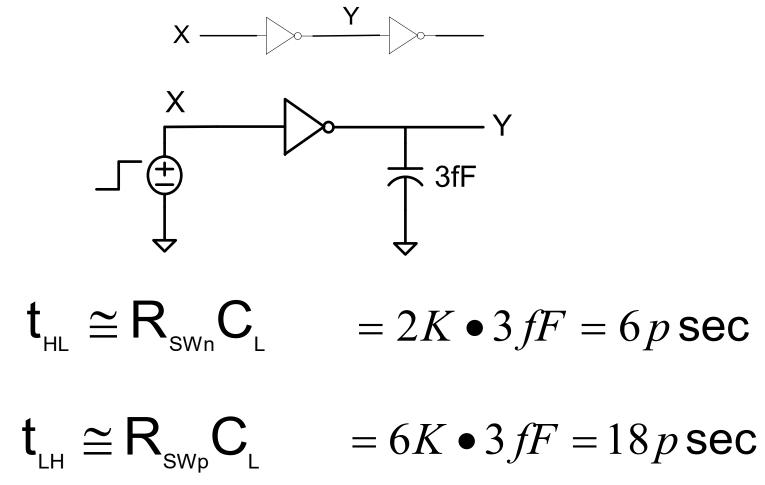


What would be the maximum clock rate for acceptable operation?

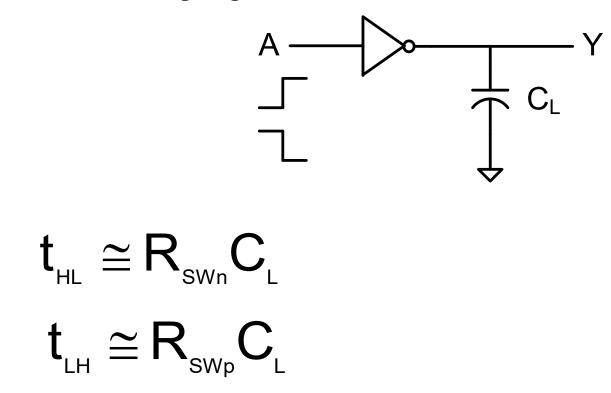


What would be the implications of allowing for 10 levels of logic and 10 loads (FanOut=10)?

Example: What is the delay of a minimum-sized inverter driving another identical device? SUMMARY



This is very fast but even the small 1.5fF capacitors are not negligible ! These capacitors play a key role in determining the speed of a circuit ! Response time of logic gates



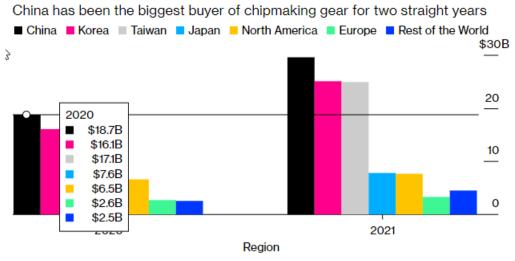
- Logic Circuits can operate very fast
- Extremely small parasitic capacitances play key role in speed of a circuit

Some Observations about Technology and Politics

Are the larger feature size technologies still used by industry today in the US or abroad?

GlobalData predicts that the <u>Chinese market will play a</u> <u>much smaller role for foreign suppliers by 2030</u>. More than 90% of the chips sold and used worldwide involve lowprocess production technology.

https://www.investmentmonitor.ai/analysis/china-lead-global-semiconductor-growth 2030#:~:text=Global %20semiconductor%20industry%20revolves%20around,Samsung 20Electronics%20and%20SK%20Hynix.



Source: SEMI

Some Observations about Technology and Politics

Sept 2022

https://technode.com/2021/03/04/where-china-is-investing-in-semiconductors-in-charts/

China is the world's largest consumer of semiconductors, and the lion's share of revenue from purchasing these chips go to foreign firms. China consumed \$143.4 billion worth of wafers in 2020, and just 5.9% of them were <u>produced</u> by companies headquartered in China.

The Chips Act of 2022

\$52 billion grant over five years to help grow the domestic semiconductor manufacturing. \$2 billion of which is to explicitly focus on legacy chip production. These chips are essential to the auto industry, the military, and other industries critical to our national security interests. The CHIPS and Science Act: Here's what's in it

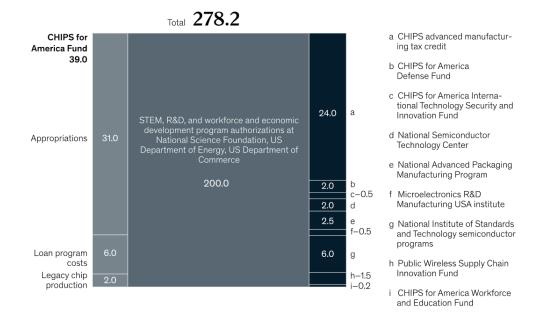
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F

By the numbers: The CHIPS Act directs \$280 billion in spending over the next ten years. The majority—\$200 billion—is for scientific R&D and commercialization. Some \$52.7 billion is for semiconductor manufacturing, R&D, and workforce development, with another \$24 billion worth of tax credits for chip production. There is \$3 billion slated for programs aimed at leading-edge technology and wireless supply chains.

The CHIPS and Science Act of 2022 directs \$280 billion in spending over the next ten years, with the bulk for scientific R&D.

CHIPS and Science Act funding for 2022-26, \$ billion



Source: Creating Helpful Incentives to Produce Semiconductors (CHIPS) and Science Act of 2022, H.R. 4346, 117th Cong. (2022)

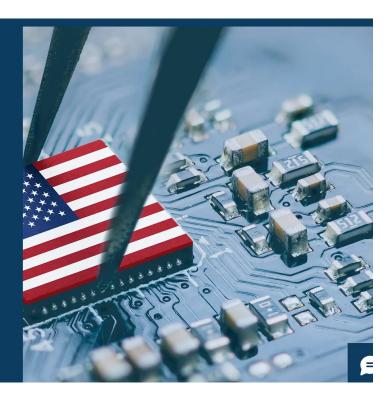


How do I get CHIPS Act Funding?

<u>Breaking News</u>: The application for wafer manufacturers and suppliers of materials and equipment (e.g., chemicals and tools) was just released. Read the details <u>here</u>.

\$53 billion is available for semiconductor manufacturing and R&D, plus a 25% refundable tax credit for qualified CapEx. See below to discover where your business fits in

Need help? Book an appointment with our professional grant writing team <u>here</u> or email us: equity@chipsact.com







Stay Safe and Stay Healthy !

End of Lecture 7